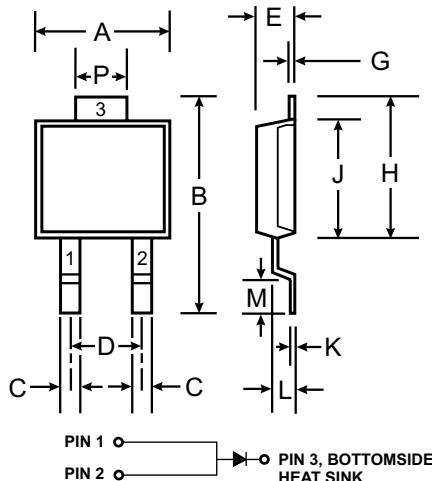


Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- Very Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: POWERMITE®3 Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Marking: Type Number
- Weight: 0.072 grams (approx.)



Note: Pins 1 & 2 must be electrically connected at the printed circuit board.

| POWERMITE®3 | | |
|-------------|----------|------|
| Dim | Min | Max |
| A | 4.03 | 4.09 |
| B | 6.40 | 6.61 |
| C | .889 NOM | |
| D | 1.83 NOM | |
| E | 1.10 | 1.14 |
| G | .178 NOM | |
| H | 5.01 | 5.17 |
| J | 4.37 | 4.43 |
| K | .178 NOM | |
| L | .71 | .77 |
| M | .36 | .46 |
| P | 1.73 | 1.83 |

All Dimensions in mm

Maximum Ratings

@ TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

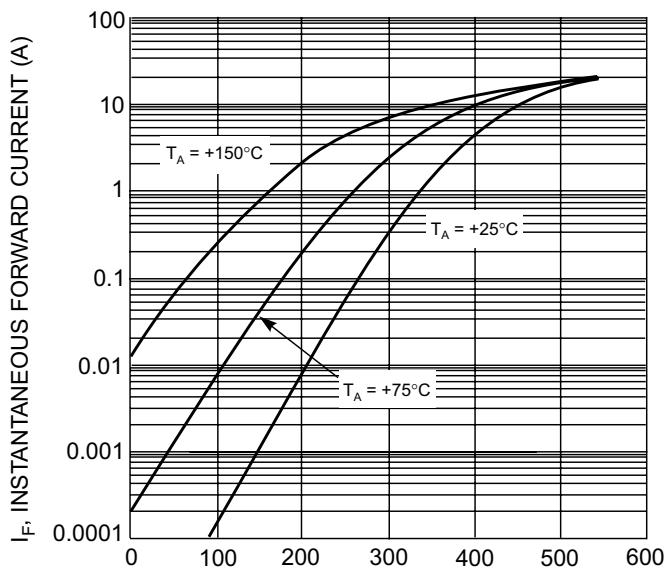
| Characteristic | Symbol | Value | Unit |
|---|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RMM} V _{RWM} V _R | 40 | V |
| RMS Reverse Voltage | V _{R(RMS)} | 28 | V |
| Average Rectified Output Current @ TS = 88°C | I _O | 10 | A |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method) | I _{FSM} | 150 | A |
| Typical Thermal Resistance Junction to Soldering Point | R _{θJS} | 1.5 | °C/W |
| Operating Temperature Range | T _j | -65 to +125 | °C |
| Storage Temperature Range | T _{STG} | -65 to +150 | °C |

Electrical Characteristics

@ TA = 25°C unless otherwise specified

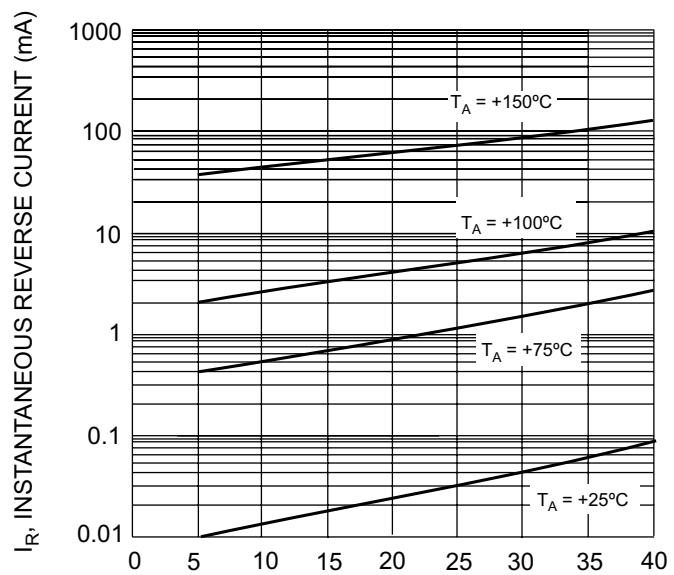
| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|------------------------------------|--------------------|-----|--------------|--------------|------|--|
| Reverse Breakdown Voltage (Note 1) | V _{(BR)R} | 40 | — | — | V | I _R = 1mA |
| Forward Voltage (Note 1) | V _{FM} | — | 0.45 0.47 | 0.49 0.51 | V | I _F = 8A, T _S = 25°C I _F = 8A, T _S = 125°C I _F = 10A, T _S = 25°C I _F = 10A, T _S = 125°C |
| Peak Reverse Current (Note 1) | I _{RM} | — | 0.1 12.5 | 0.3 25 | mA | T _S = 25°C, V _R = 35V T _S = 100°C, V _R = 35V |
| Junction Capacitance | C _j | — | 700 | — | pF | f = 1.0MHz, V _R = 4.0V DC |

Notes: 1. Short duration test pulse used to minimize self-heating effect.



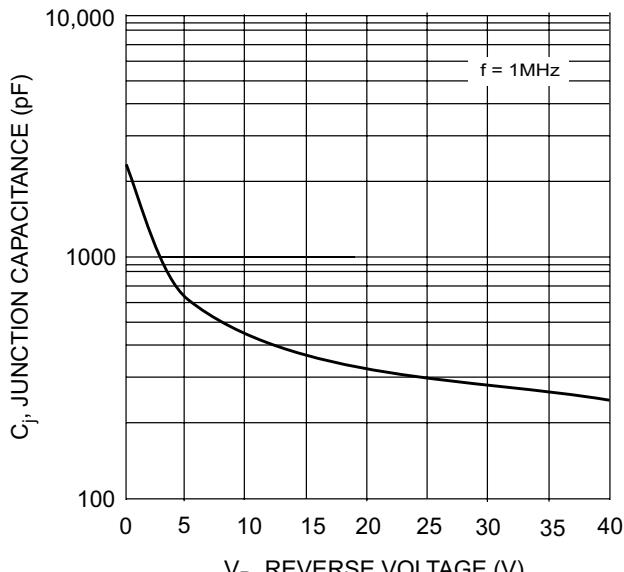
V_F , INSTANTANEOUS FORWARD VOLTAGE (mV)

Fig. 1 Typical Forward Characteristics



V_R , INSTANTANEOUS REVERSE VOLTAGE (V)

Fig. 2 Typical Reverse Characteristics



V_R , REVERSE VOLTAGE (V)

Fig. 3 Typical Junction Capacitance vs. Reverse Voltage